

$|| \theta_{cA} ||$  (19)  
 C/W  
 ts  
 $90^{\circ}\text{C/W}$   
 $^{\circ}\text{C/W} + 90^{\circ}\text{C/W}$   
 $^{\circ}\text{C}$

case output voltage  
 junction temperature  
 der these conditions.  
 ambient up to  $119^{\circ}\text{C}$   
 temperature rating.  
 of the output short-

(20)  
 mperature rating of  
 out should not be  
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102 should not be  
 using the package  
 about  $90^{\circ}\text{C}$  per watt.  
 usually increase the  
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 change in thermal  
 rmance. Removing  
 e in the 1 f region.



# OPA111

MILITARY & DIE  
VERSIONS  
AVAILABLE

OPA111

2

OPERATIONAL AMPLIFIERS

## Low Noise Precision *Difet*<sup>®</sup> OPERATIONAL AMPLIFIER

### FEATURES

- LOW NOISE: 100% tested,  $8\text{nV}/\sqrt{\text{Hz}}$  max at 10kHz
- LOW BIAS CURRENT:  $1\text{pA}$  max
- LOW OFFSET:  $250\mu\text{V}$  max
- LOW DRIFT:  $1\mu\text{V}/^{\circ}\text{C}$  max
- HIGH OPEN-LOOP GAIN: 120dB min
- HIGH COMMON-MODE REJECTION: 100dB min

### APPLICATIONS

- PRECISION INSTRUMENTATION
- DATA ACQUISITION
- TEST EQUIPMENT
- OPTOELECTRONICS
- MEDICAL EQUIPMENT—CAT SCANNER
- RADIATION HARD EQUIPMENT

### DESCRIPTION

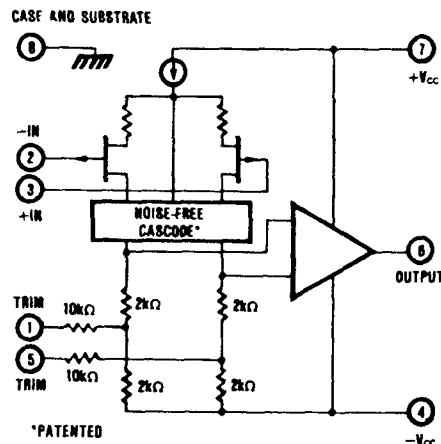
The OPA111 is a precision monolithic dielectrically-isolated FET (*Difet*<sup>®</sup>) operational amplifier. Outstanding performance characteristics allow its use in the most critical instrumentation applications.

Noise, bias current, voltage offset, drift, open-loop gain, common-mode rejection, and power supply rejection are superior to BIFET<sup>®</sup> amplifiers.

Very-low bias current is obtained by dielectric isolation with on-chip guarding.

Laser trimming of thin-film resistors gives very-low offset and drift. Extremely-low noise is achieved with new circuit design techniques (patented). A new cascode design allows high precision input specifications and reduced susceptibility to flicker noise.

Standard 741 pin configuration allows upgrading of existing designs to higher performance levels.



OPA111 SIMPLIFIED CIRCUIT

BIFET<sup>®</sup>National Semiconductor Corp., *Difet*<sup>®</sup>Burr-Brown Corp.

International Airport Industrial Park - P.O. Box 11400 - Tucson, Arizona 85734 - Tel: (602) 746-1111 - Twx: 910-952-1111 - Cable: BBRCORP - Telex: 66-5401

PDS-526G

# SPECIFICATIONS

## ELECTRICAL

At  $V_{CC} = \pm 15\text{VDC}$  and  $T_A = +25^\circ\text{C}$  unless otherwise noted. Pin 8 connected to ground.

PARAMETER	CONDITIONS	OPA111AM			OPA111BM			OPA111SM			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
<b>INPUT</b>											
<b>NOISE</b>											
Voltage, $f_o = 10\text{Hz}$	100% tested		40	80		30	60		40	80	$\text{nV}/\sqrt{\text{Hz}}$
$f_o = 100\text{Hz}$	100% tested		15	40		11	30		15	40	$\text{nV}/\sqrt{\text{Hz}}$
$f_o = 1\text{kHz}$	100% tested		8	15		7	12		8	15	$\text{nV}/\sqrt{\text{Hz}}$
$f_o = 10\text{kHz}$	100% tested		6	8		6	8		6	8	$\text{nV}/\sqrt{\text{Hz}}$
$f_B = 10\text{Hz to } 10\text{kHz}$	100% tested		0.7	1.2		0.6	1.0		0.7	1.2	$\mu\text{V, rms}$
$f_B = 0.1\text{Hz to } 10\text{Hz}$	"		1.6	3.3		1.2	2.5		1.6	3.3	$\mu\text{V, p-p}$
Current, $f_B = 0.1\text{Hz to } 10\text{Hz}$	"		9.5	15		7.5	12		9.5	15	$\text{fA, p-p}$
$f_B = 0.1\text{Hz thru } 20\text{kHz}$	"		0.5	0.8		0.4	0.6		0.5	0.8	$\text{fA}/\sqrt{\text{Hz}}$
<b>OFFSET VOLTAGE<sup>(1)</sup></b>											
Input Offset Voltage	$V_{cm} = 0\text{VDC}$		$\pm 100$	$\pm 500$		$\pm 50$	$\pm 250$		$\pm 100$	$\pm 500$	$\mu\text{V}$
Average Drift	$T_A = T_{MIN}$ to $T_{MAX}$		$\pm 2$	$\pm 5$		$\pm 0.5$	$\pm 1$		$\pm 2$	$\pm 5$	$\mu\text{V}/^\circ\text{C}$
Supply Rejection	$V_{CC} = \pm 10\text{V to } \pm 18\text{V}$	90	110		100	110		90	110		$\text{dB}$
			$\pm 3$	$\pm 31$		$\pm 3$	$\pm 10$		$\pm 3$	$\pm 31$	$\mu\text{V/V}$
<b>BIAS CURRENT<sup>(2)</sup></b>											
Input Bias Current	$V_{cm} = 0\text{VDC}$		$\pm 0.8$	$\pm 2$		$\pm 0.5$	$\pm 1$		$\pm 0.8$	$\pm 2$	$\text{pA}$
<b>OFFSET CURRENT<sup>(2)</sup></b>											
Input Offset Current	$V_{cm} = 0\text{VDC}$		$\pm 0.5$	$\pm 1.5$		$\pm 0.25$	$\pm 0.75$		$\pm 0.5$	$\pm 1.5$	$\text{pA}$
<b>IMPEDANCE</b>											
Differential			$10^{13} \parallel 1$			$10^{13} \parallel 1$			$10^{13} \parallel 1$		$\Omega \parallel \text{pF}$
Common-Mode			$10^{14} \parallel 3$			$10^{14} \parallel 3$			$10^{14} \parallel 3$		$\Omega \parallel \text{pF}$
<b>VOLTAGE RANGE</b>											
Common-Mode Input Range	$V_{IN} = \pm 10\text{VDC}$	$\pm 10$	$\pm 11$		$\pm 10$	$\pm 11$		$\pm 10$	$\pm 11$		$\text{V}$
Common-Mode Rejection		90	110		100	110		90	110		$\text{dB}$
<b>OPEN-LOOP GAIN, DC</b>											
Open-Loop Voltage Gain	$R_L \geq 2\text{k}\Omega$	114	125		120	125		114	125		$\text{dB}$
<b>FREQUENCY RESPONSE</b>											
Unity Gain, Small Signal			2			2			2		$\text{MHz}$
Full Power Response	$20\text{V p-p}, R_L = 2\text{k}$	16	32		16	32		16	32		$\text{kHz}$
Slew Rate	$V_o = \pm 10\text{V}, R_L = 2\text{k}$	1	2		1	2		1	2		$\text{V}/\mu\text{sec}$
Settling Time, 0.1%	Gain = -1, $R_L = 2\text{k}$		6			6			6		$\mu\text{sec}$
0.01%	10V step		10			10			10		$\mu\text{sec}$
Overload Recovery, 50% Overdrive <sup>(3)</sup>	Gain = -1		5			5			5		$\mu\text{sec}$
<b>RATED OUTPUT</b>											
Voltage Output	$R_L = 2\text{k}\Omega$	$\pm 11$	$\pm 12$		$\pm 11$	$\pm 12$		$\pm 11$	$\pm 12$		$\text{V}$
Current Output	$V_o = \pm 10\text{VDC}$	$\pm 5.5$	$\pm 10$		$\pm 5.5$	$\pm 10$		$\pm 5.5$	$\pm 10$		$\text{mA}$
Output Resistance	DC, open loop		100			100			100		$\Omega$
Load Capacitance Stability	Gain = +1		1000			1000			1000		$\text{pF}$
Short Circuit Current		10	40		10	40		10	40		$\text{mA}$
<b>POWER SUPPLY</b>											
Rated Voltage			$\pm 15$			$\pm 15$			$\pm 15$		$\text{VDC}$
Voltage Range, Derated Performance		$\pm 5$		$\pm 18$	$\pm 5$		$\pm 18$	$\pm 5$		$\pm 18$	$\text{VDC}$
Current, Quiescent	$I_o = 0\text{mA DC}$		2.5	3.5		2.5	3.5		2.5	3.5	$\text{mA}$
<b>TEMPERATURE RANGE</b>											
Specification	Ambient temp.	-25		+85	-25		+85	-55		+125	$^\circ\text{C}$
Operating	Ambient temp.	-55		+125	-55		+125	-55		+125	$^\circ\text{C}$
Storage	Ambient temp.	-65		+150	-65		+150	-65		+150	$^\circ\text{C}$
# Junction-Ambient			200			200			200		$^\circ\text{C}/\text{W}$

NOTES: (1) Sample tested—this parameter is guaranteed. (2) Offset voltage, offset current, and bias current are measured with the units fully warmed up. (3) Overload recovery is defined as the time required for the output to return from saturation to linear operation following the removal of a 50% input overdrive.

## ELECTRICAL

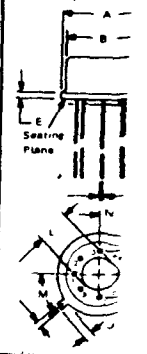
At  $V_{CC} = \pm 15\text{VDC}$

PARAMETER	Specification Range
<b>TEMPERATURE RANGE</b>	
<b>INPUT</b>	
OFFSET VOLTAGE	Input Offset Voltage
Offset Voltage	Average Drift
Supply Rejection	Supply Rejection
<b>BIAS CURRENT<sup>(1)</sup></b>	
Input Bias Current	Input Bias Current
<b>OFFSET CURRENT<sup>(2)</sup></b>	
Input Offset Current	Input Offset Current
<b>VOLTAGE RANGE</b>	
Common-Mode Input Range	Common-Mode Rejection
<b>OPEN-LOOP GAIN</b>	
Open-Loop Voltage Gain	Open-Loop Voltage Gain
<b>RATED OUTPUT</b>	
Voltage Output	Current Output
Output Resistance	Short Circuit Current
<b>POWER SUPPLY</b>	
Current, Quiescent	Current, Quiescent

NOTES: (1) Offset

## MECHANICAL

NOTE: Leads in true position (0.25mm) at MMC



## ORDERING

Model  
OPA111AM  
OPA111BM  
OPA111SM

## BURN-IN SCORE

OPA111AM-E  
OPA111BM-E  
OPA111SM-E

NOTE: (1) Or eq.  
Burr-Bro

### ELECTRICAL [FULL TEMPERATURE RANGE SPECIFICATIONS]

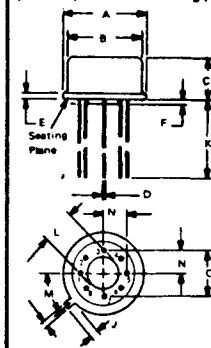
At  $V_{CC} = \pm 15\text{VDC}$  and  $T_A = T_{MIN}$  to  $T_{MAX}$  unless otherwise noted.

PARAMETER	CONDITIONS	OPA111AM			OPA111BM			OPA111SM			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
<b>TEMPERATURE RANGE</b>											
Specification Range	Ambient temp.	-25		+85	-25		+85	-55		+125	°C
<b>INPUT</b>											
OFFSET VOLTAGE <sup>(1)</sup>	$V_{cm} = 0\text{VDC}$		±220	±1000		±110	±500		±300	±1500	μV
Input Offset Voltage			±2	±5		±0.5	±1		±2	±5	μV/°C
Average Drift			86	100		90	100		86	100	dB
Supply Rejection	$V_{CC} = \pm 10\text{V}$ to $\pm 18\text{V}$		±10	±50		±10	±32		±10	±50	μV/V
<b>BIAS CURRENT<sup>(1)</sup></b>											
Input Bias Current	$V_{cm} = 0\text{VDC}$		±50	±250		±30	±130		±820	±4100	pA
<b>OFFSET CURRENT<sup>(1)</sup></b>											
Input Offset Current	$V_{cm} = 0\text{VDC}$		±30	±200		±15	±100		±510	±3100	pA
<b>VOLTAGE RANGE</b>											
Common-Mode Input Range		±10	±11		±10	±11		±10	±11		V
Common-Mode Rejection	$V_{CM} = \pm 10\text{VDC}$	86	100		90	100		86	100		dB
<b>OPEN-LOOP GAIN, DC</b>											
Open-Loop Voltage Gain	$R_L \geq 2\text{k}\Omega$	110	120		114	120		110	120		dB
<b>RATED OUTPUT</b>											
Voltage Output	$R_L = 2\text{k}\Omega$	±10.5	±11		±11	±11.5		±11	±11.5		V
Current Output	$V_o = \pm 10\text{VDC}$	±5.25	±10		±5.25	±10		±5.25	±10		mA
Short Circuit Current	$V_o = 0\text{VDC}$	10	40		10	40		10	40		mA
<b>POWER SUPPLY</b>											
Current, Quiescent	$I_o = 0\text{mADC}$	2.5	3.5		2.5	3.5		2.5	3.5		mA

NOTES: (1) Offset voltage, offset current, and bias current are measured with the units fully warmed up.

### MECHANICAL "M" PACKAGE TO-99 (Hermetic)

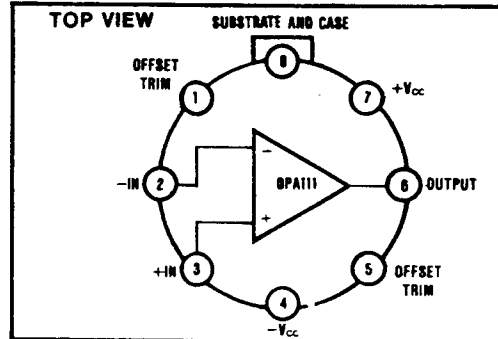
NOTE: Leads in true position within .010" (.25mmR) at MMC at seating plane.



Pin numbers shown for reference only. Numbers may not be marked on package. Pin material and plating composition conform to Method 2003 (solderability) of MIL-STD-883 (except paragraph 3.2).

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.335	.370	8.51	9.40
B	.305	.335	7.75	8.51
C	.185	.185	4.19	4.70
D	.016	.021	0.41	0.53
E	.010	.040	0.25	1.02
F	.010	.040	0.25	1.02
G	200 BASIC		5.08 BASIC	
H	.026	.034	0.71	0.86
J	.029	.045	0.74	1.14
K	.500	—	12.7	—
L	.110	.180	2.79	4.06
M	45° BASIC		45° BASIC	
N	.085	.105	2.41	2.67

### CONNECTION DIAGRAM



### ORDERING INFORMATION

Model	Package	Temperature Range	Offset Voltage, max (μV)
OPA111AM	TO-99	-25°C to +85°C	±500
OPA111BM	TO-99	-25°C to +85°C	±250
OPA111SM	TO-99	-55°C to +125°C	±500

### BURN-IN SCREENING OPTION

Model	Package	Temperature Range	Burn-In Temp. (100h) <sup>(1)</sup>
OPA111AM-BI	TO-99	-25°C to +85°C	+125°C
OPA111BM-BI	TO-99	-25°C to +85°C	+125°C
OPA111SM-BI	TO-99	-25°C to +85°C	+125°C

NOTE: (1) Or equivalent combination of time and temperature.

MAX	UNITS
80	nV/√Hz
40	nV/√Hz
15	nV/√Hz
8	nV/√Hz
1.2	μV, rms
3.3	μV, p-p
15	IA, p-p
0.8	IA/√Hz
±500	μV
±5	μV/°C
	dB
±31	μV/V
	pA
±2	pA
±1.5	pA
	Ω    pF
	Ω    pF
	V
	dB
	dB
	MHz
	kHz
	V/μsec
	μsec
	μsec
	V
	mA
	Ω
	pF
	mA
	VDC
±18	VDC
3.5	mA
+125	°C
+125	°C
+150	°C
	°C/W

units fully warmed  
50% input overdrive.

OPA111

2

OPERATIONAL AMPLIFIERS

## ABSOLUTE MAXIMUM RATINGS

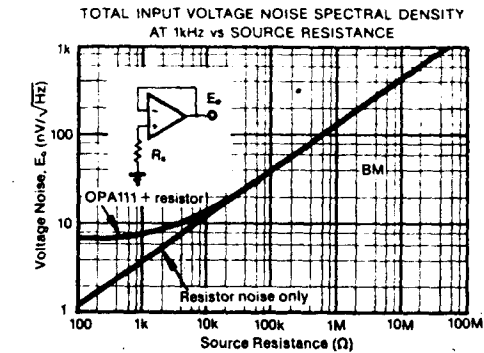
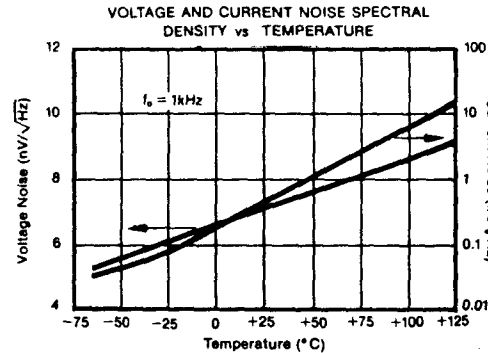
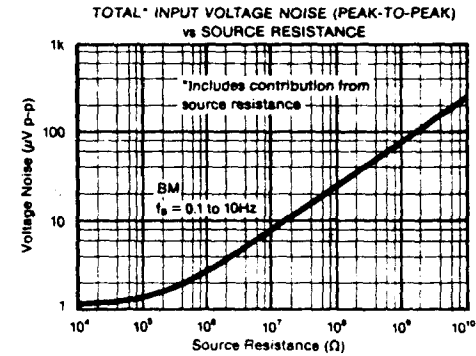
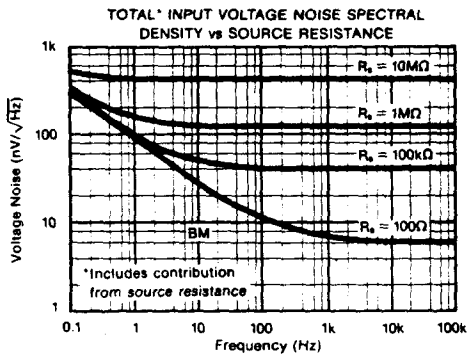
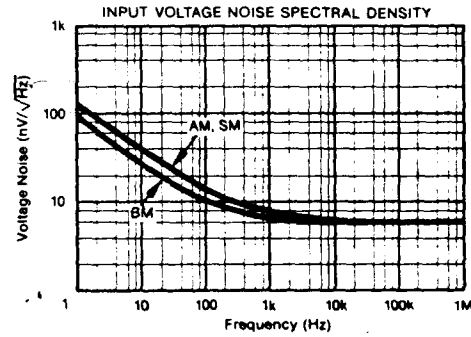
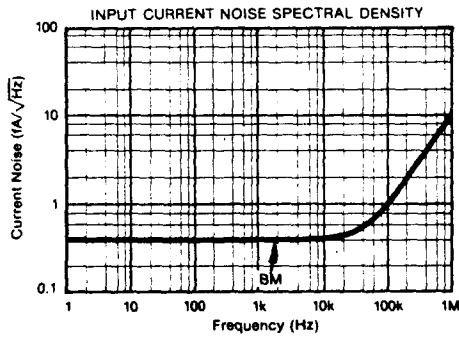
Supply	±18VDC
Internal Power Dissipation <sup>(1)</sup>	500mW
Differential Input Voltage <sup>(2)</sup>	±36VDC
Input Voltage Range <sup>(2)</sup>	±18VDC
Storage Temperature Range	-65°C to +150°C
Operating Temperature Range	-55°C to +125°C
Lead Temperature (soldering, 10 seconds)	+300°C
Output Short Circuit Duration <sup>(3)</sup>	Continuous
Junction Temperature	+175°C

### NOTES:

- (1) Packages must be derated based on  $\theta_{JC} = 150^\circ\text{C/W}$  or  $\theta_{JA} = 300^\circ\text{C/W}$ .
- (2) For supply voltages less than  $\pm 18\text{VDC}$  the absolute maximum input voltage is equal to  $+18\text{V} > V_{IN} > -V_{CC} - 6\text{V}$ . See Figure 2.
- (3) Short circuit may be to power supply common only. Rating applies to  $+25^\circ\text{C}$  ambient. Observe dissipation limit and  $T_J$ .

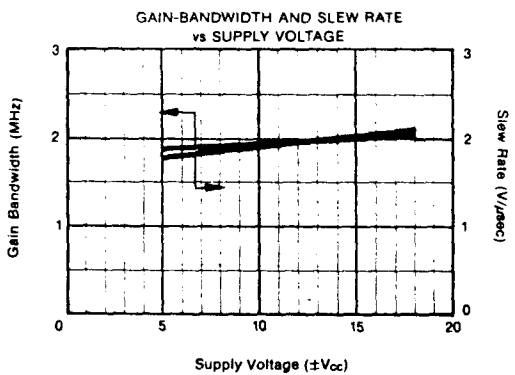
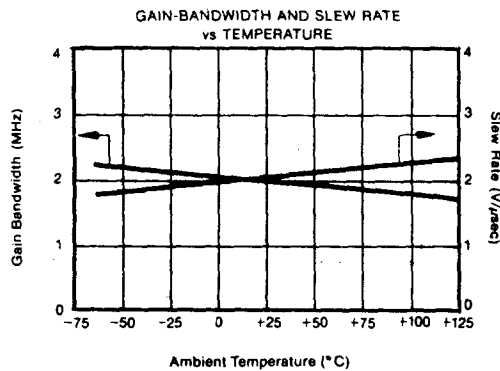
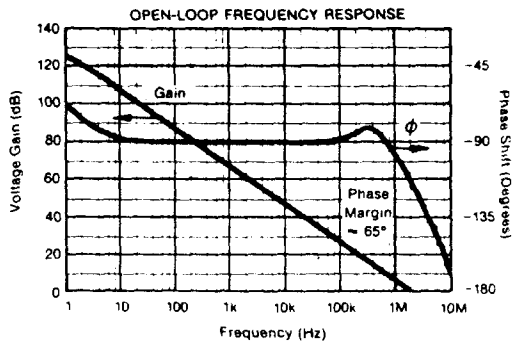
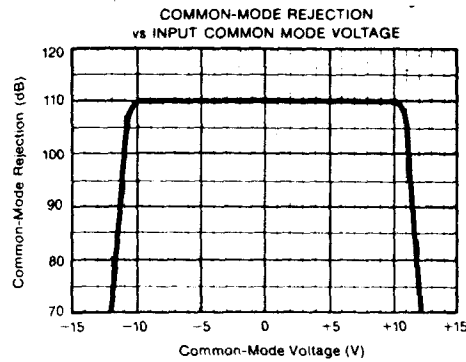
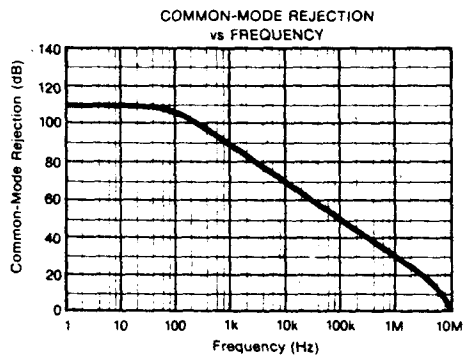
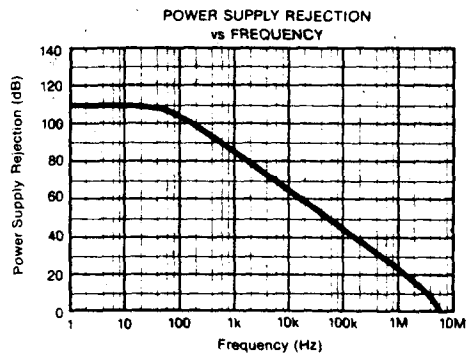
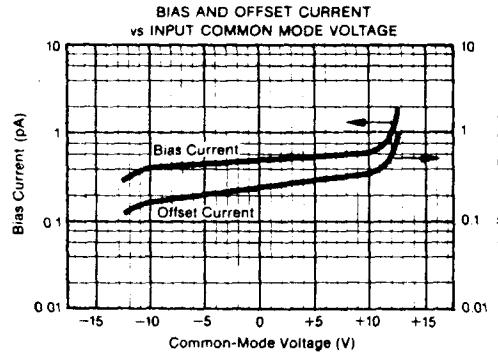
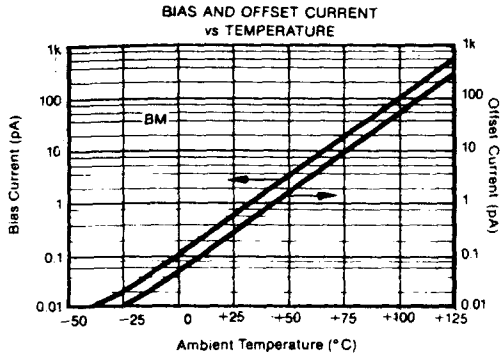
## TYPICAL PERFORMANCE CURVES

$T_A = +25^\circ\text{C}$ ,  $V_{CC} = \pm 15\text{VDC}$  unless otherwise noted.



# TYPICAL PERFORMANCE CURVES [CONT]

$T_a = +25^\circ\text{C}$ ,  $V_{cc} = \pm 15\text{VDC}$  unless otherwise noted.



OPA111

2

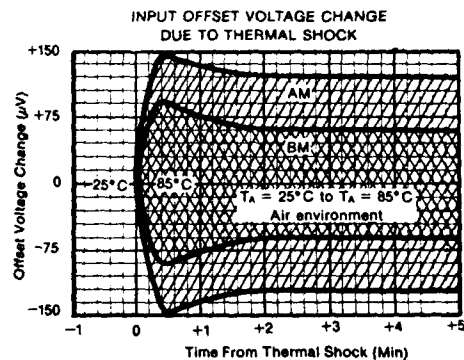
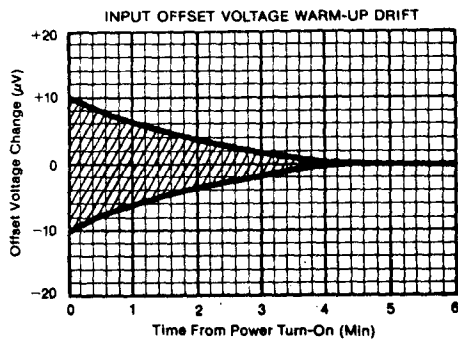
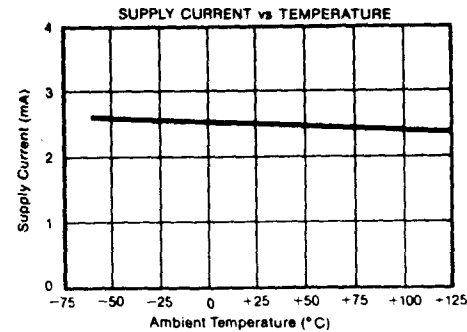
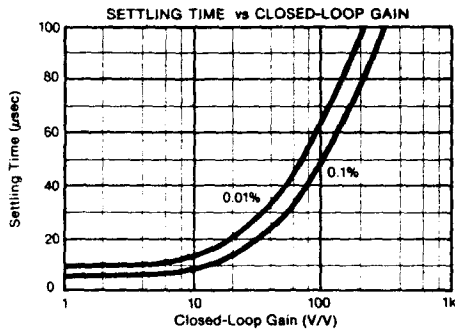
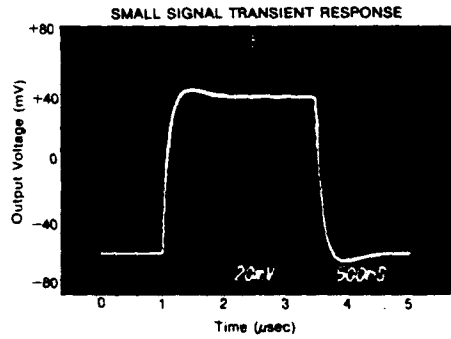
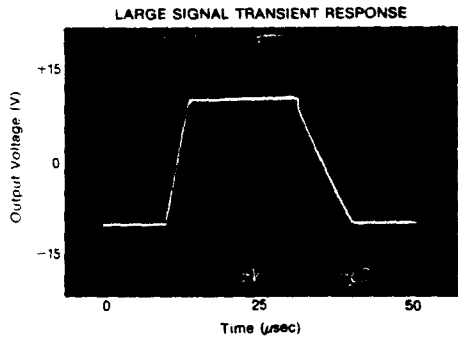
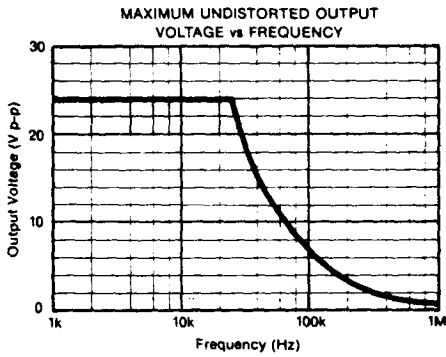
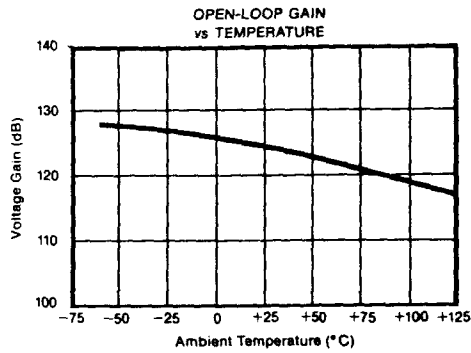
OPERATIONAL AMPLIFIERS

300°C/W.  
maximum input  
applies to



## TYPICAL PERFORMANCE CURVES [CONT]

$T_A = +25^\circ\text{C}$ ,  $V_{CC} = \pm 15\text{VDC}$  unless otherwise noted.



## APPLI INFO

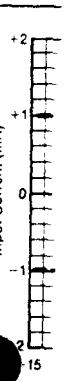
### OFFSET

The OPA require no most ampli can chang each 100µ 1) is simil AD547. 7 by leaving

FIGURE

### INPUT

Conventi require e inputs a input FE biased. N loss of - Unlike E input cu greater i series re up to ± lost.



FIGUR

## APPLICATIONS INFORMATION

### OFFSET VOLTAGE ADJUSTMENT

The OPA111 offset voltage is laser-trimmed and will require no further trim for most applications. As with most amplifiers, externally trimming the remaining offset can change drift performance by about  $0.3\mu\text{V}/^\circ\text{C}$  for each  $100\mu\text{V}$  of adjusted offset. Note that the trim (Figure 1) is similar to operational amplifiers such as 741 and AD547. The OPA111 can replace most other amplifiers by leaving the external null circuit unconnected.

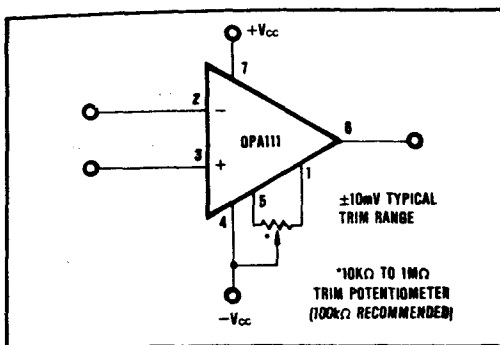


FIGURE 1. Offset Voltage Trim.

### INPUT PROTECTION

Conventional monolithic FET operational amplifiers require external current-limiting resistors to protect their inputs against destructive currents that can flow when input FET gate-to-substrate isolation diodes are forward-biased. Most BIFET amplifiers can be destroyed by the loss of  $-V_{cc}$ .

Unlike BIFET amplifiers, the *Difet* OPA111 requires input current limiting resistors only if its input voltage is greater than 6 volts more negative than  $=V_{cc}$ . A  $10k\Omega$  series resistor will limit input current to a safe level with up to  $\pm 15\text{V}$  input levels even if both supply voltages are lost.

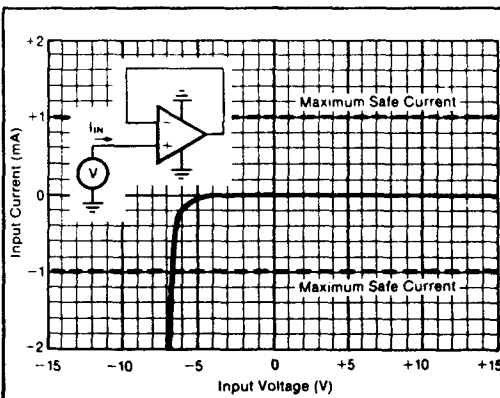


FIGURE 2. Input Current vs Input Voltage with  $\pm V_{cc}$  Pins Grounded.

Static damage can cause subtle changes in amplifier input characteristics without necessarily destroying the device. In precision operational amplifiers (both bipolar and FET types), this may cause a noticeable degradation of offset voltage and drift.

Static protection is recommended when handling any precision IC operational amplifier.

### GUARDING AND SHIELDING

As in any situation where high impedances are involved, careful shielding is required to reduce "hum" pickup in input leads. If large feedback resistors are used, they should also be shielded along with the external input circuitry.

Leakage currents across printed circuit boards can easily exceed the bias current of the OPA111. To avoid leakage problems, it is recommended that the signal input lead of the OPA111 be wired to a Teflon standoff. If the OPA111 is to be soldered directly into a printed circuit board, utmost care must be used in planning the board layout. A "guard" pattern should completely surround the high impedance input leads and should be connected to a low impedance point which is at the signal input potential.

The amplifier case should be connected to any input shield or guard via pin 8. This insures that the amplifier itself is fully surrounded by guard potential, minimizing both leakage and noise pickup (see Figure 3).

If guarding is not required, pin 8 (case) should be connected to ground.

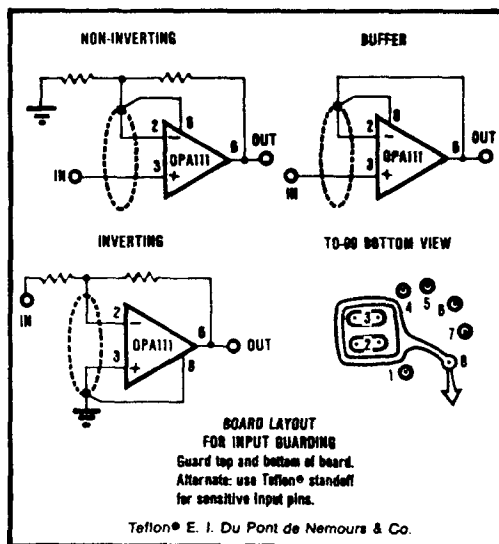


FIGURE 3. Connection of Input Guard.

### NOISE: FET VERSUS BIPOLAR

Low noise circuit design requires careful analysis of all noise sources. External noise sources can dominate in many cases, so consider the effect of source resistance on overall operational amplifier noise performance. At low source impedances, the lower voltage noise of a bipolar

operational amplifier is superior, but at higher impedances the high current noise of a bipolar amplifier becomes a serious liability. Above about 15kΩ the OPA111 will have lower total noise than an OP-27 (see Figure 4).

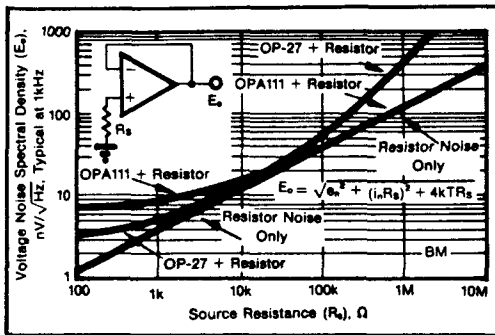


FIGURE 4. Voltage Noise Spectral Density Versus Source Resistance.

#### BIAS CURRENT CHANGE VERSUS COMMON-MODE VOLTAGE

The input bias currents of most popular BIFET operational amplifiers are affected by common-mode voltage (Figure 5). Higher input FET gate-to-drain voltage causes leakage and ionization (bias) currents to increase. Due to its cascode input stage, the extremely-low bias current of the OPA111 is not compromised by common-mode voltage.

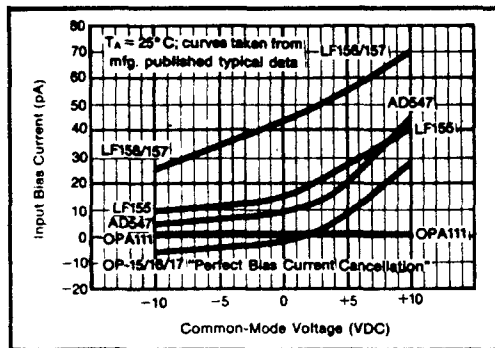


FIGURE 5. Input Bias Current Versus Common-Mode Voltage.

#### BURN-IN SCREENING

Burn-in screening is an option available for the models indicated in the Ordering Information table. Burn-in duration is 160 hours at the maximum specified grade operating temperature (or equivalent combination of time and temperature).

All units are tested after burn-in to ensure that grade specifications are met. To order burn-in, add "BI" to the base model number.

#### APPLICATIONS CIRCUITS

Figures 6 through 18 are circuit diagrams of various applications for the OPA111.

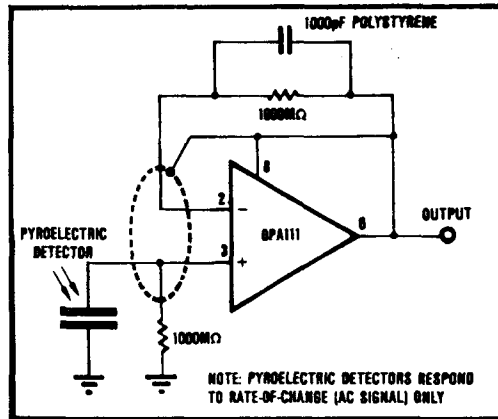


FIGURE 6. Pyroelectric Infrared Detector.

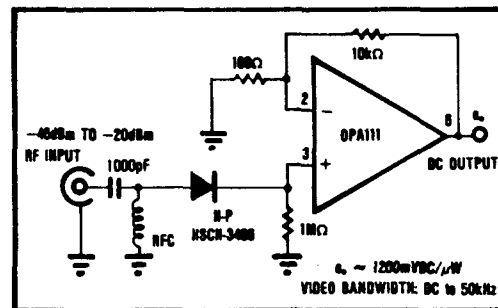


FIGURE 7. Zero-Bias Schottky Diode Square-Law RF Detector.

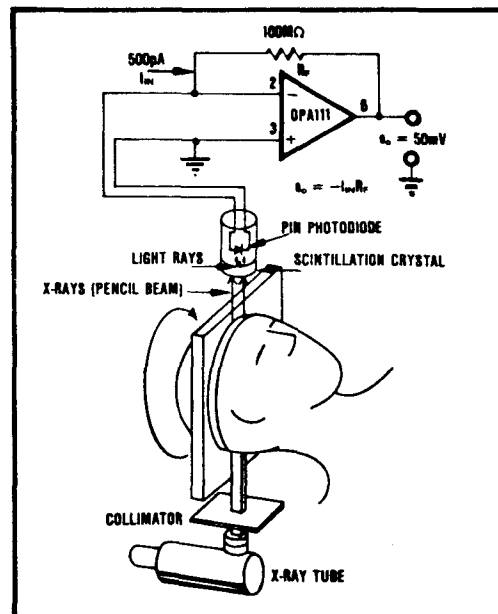


FIGURE 8. Computerized Axial Tomography (CAT) Scanner Channel Amplifier.



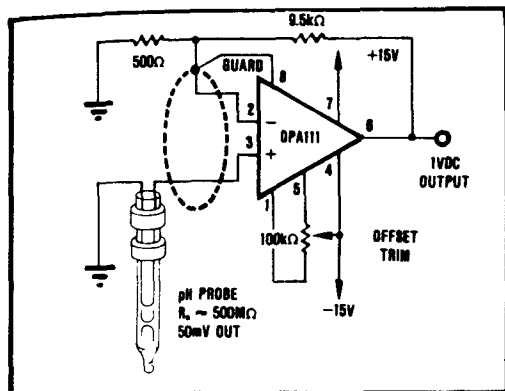


FIGURE 9. High Impedance ( $10^{14}\Omega$ ) Amplifier.

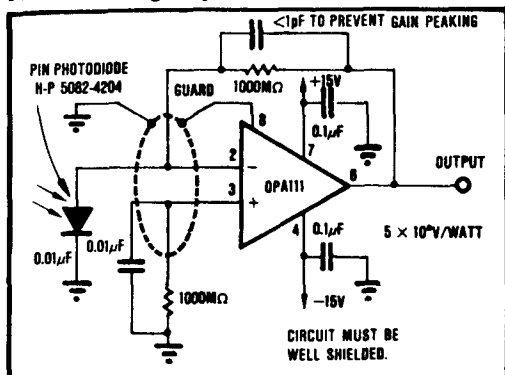


FIGURE 10. Sensitive Photodiode Amplifier.

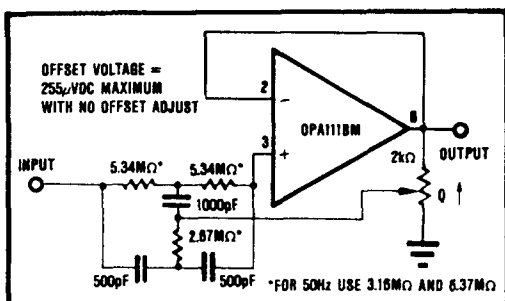


FIGURE 11. 60Hz Reject Filter.

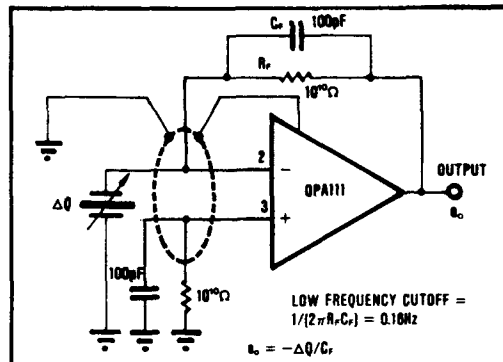


FIGURE 12. Piezoelectric Transducer Charge Amplifier.

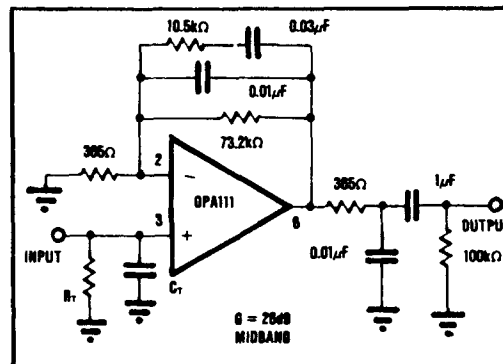


FIGURE 13. RIAA Equalized Phono Preamplifier.

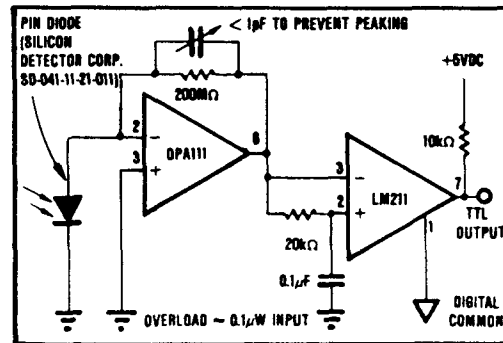


FIGURE 14. High Sensitivity (under  $1nW$ ) Fiber Optic Receiver for 9600 Baud Manchester Data.

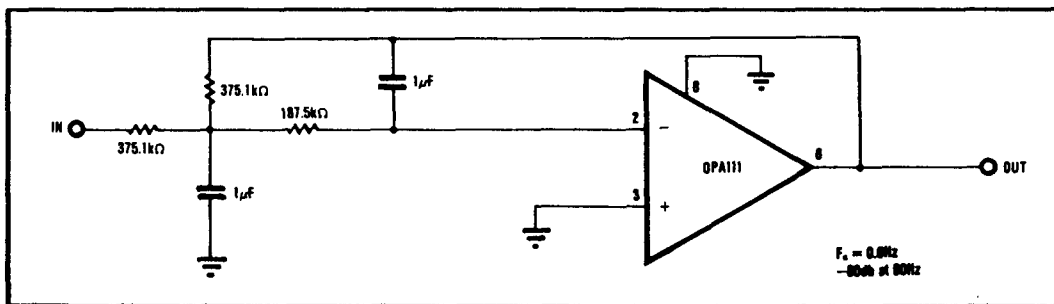


FIGURE 15. 0.6Hz Second Order Low-Pass Filter.

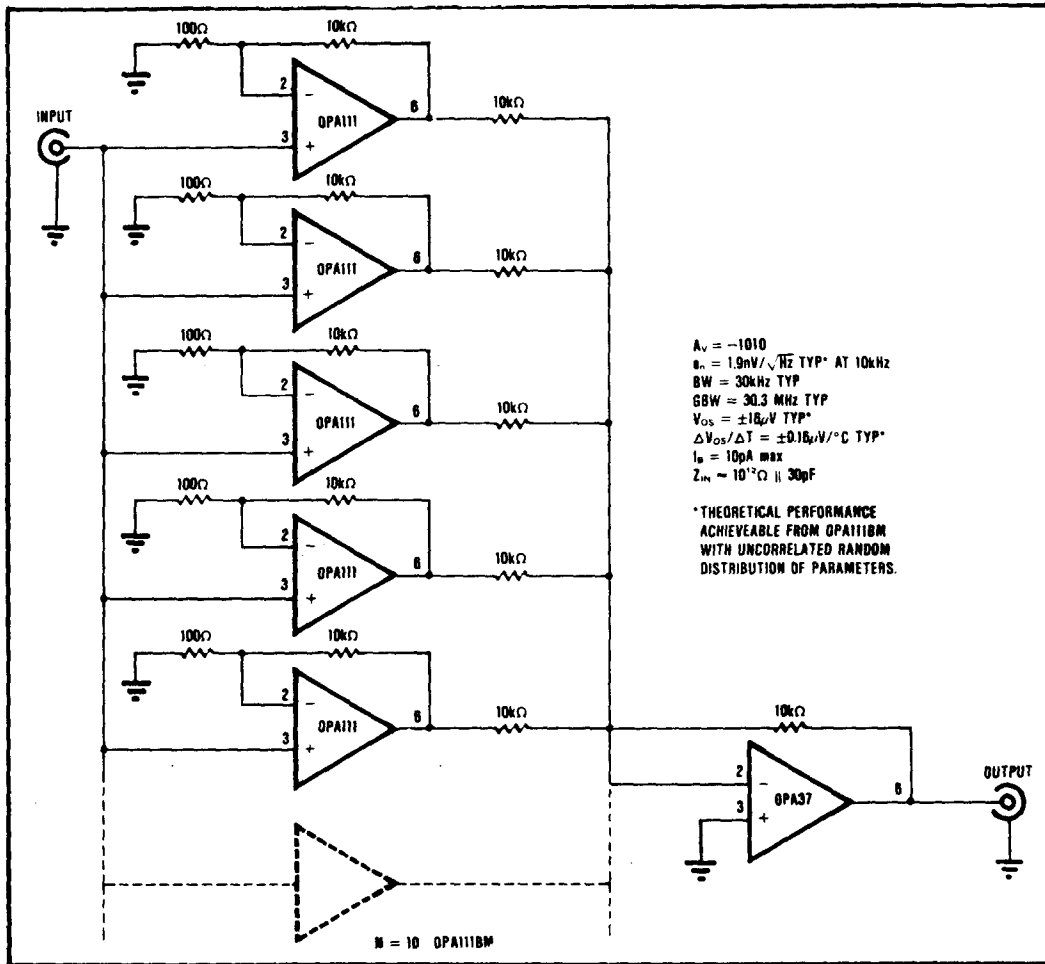


FIGURE 16. 'N' Stage Parallel-Input Amplifier For Reduced Relative Amplifier Noise At The Output.

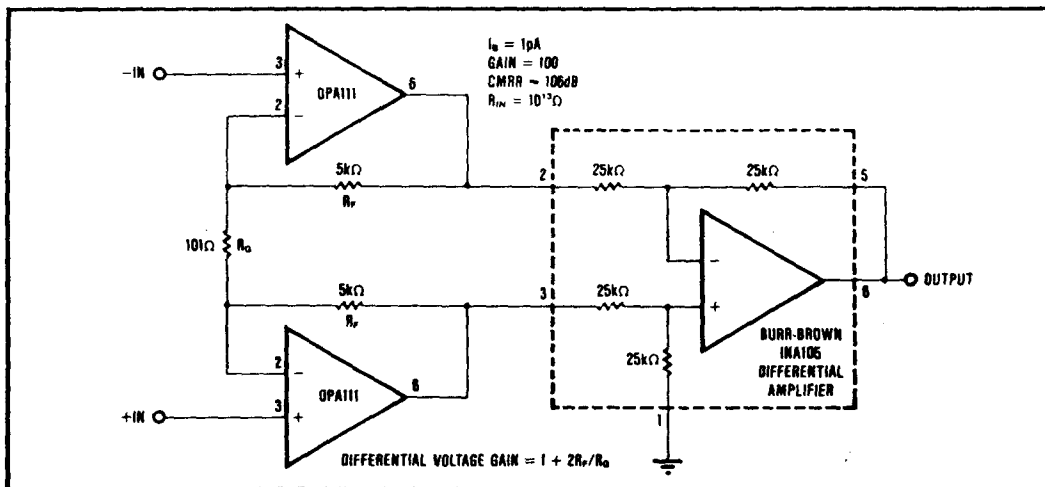


FIGURE 17. FET Input Instrumentation Amplifier.

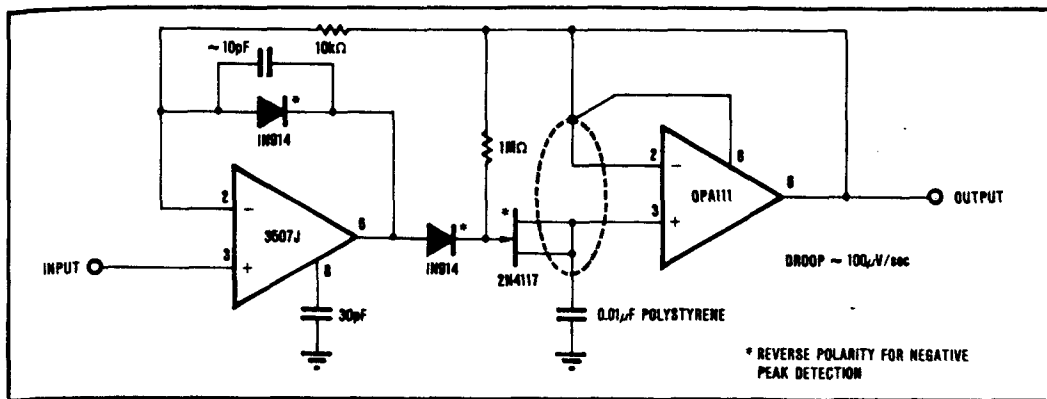


FIGURE 18. Low-Droop Positive Peak Detector.